

CDBB120-G Thru. CDBB1100-G

Reverse Voltage: 20 to 100 Volts

Forward Current: 1.0 Amp

RoHS Device

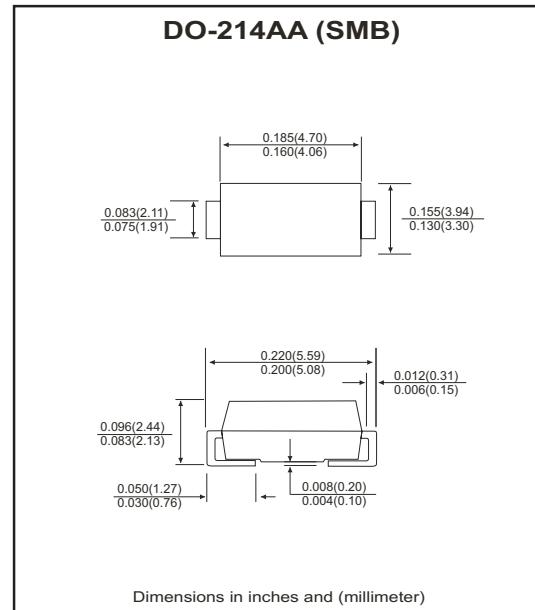


Features

- Ideal for surface mount applications.
- Easy pick and place.
- Plastic package has Underwriters Lab. flammability classification 94V-0.
- Built-in strain relief.
- Low forward voltage drop.

Mechanical data

- Case: JEDEC DO-214AA, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Polarity: Color band denotes cathode end.
- Approx. weight: 0.093 grams



Maximum Ratings and Electrical Characteristics

Parameter	Symbol	CDBB 120-G	CDBB 140-G	CDBB 160-G	CDBB 180-G	CDBB 1100-G	Units
Max. repetitive peak reverse voltage	V _{RRM}	20	40	60	80	100	V
Max. DC blocking voltage	V _{DC}	20	40	60	80	100	V
Max. RMS voltage	V _{RMS}	14	28	42	56	70	V
Peak surge forward current, 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}			30			A
Max. average forward current	I _o			1.0			A
Max. instantaneous forward voltage at 1.0A	V _F	0.50	0.70	0.85			V
Max. DC reverse current at T _A =25 °C rated DC blocking voltage T _A =100 °C	I _R		0.5	10			mA
Max. thermal resistance (Note 1)	R _{θJA} R _{θJL}		75	17			°C/W
Max. operating junction temperature	T _J		125				°C
Storage temperature	T _{STG}		-65 to +150				°C

Notes: 1. Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 0.2×0.2 inch copper pad area.

SMD Schottky Barrier Rectifiers

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RATING AND CHARACTERISTIC CURVES (CDBB120-G thru CDBB1100-G)

Fig.1 Reverse Characteristics

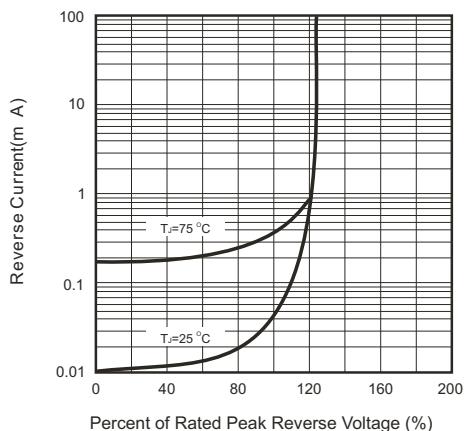


Fig.2 Forward Characteristics

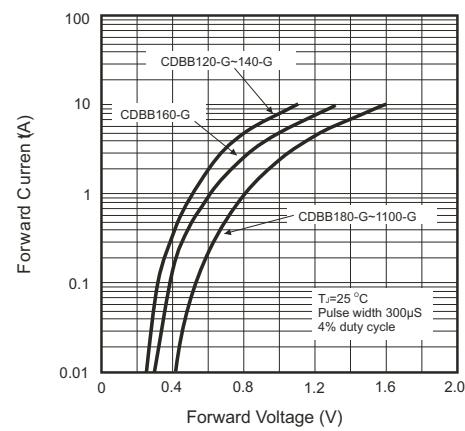


Fig.3 Junction Capacitance

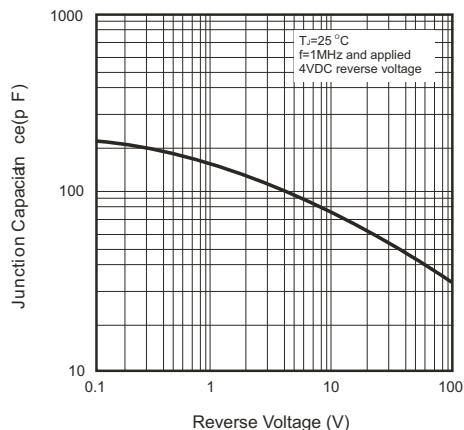


Fig.4 Current Derating Curve

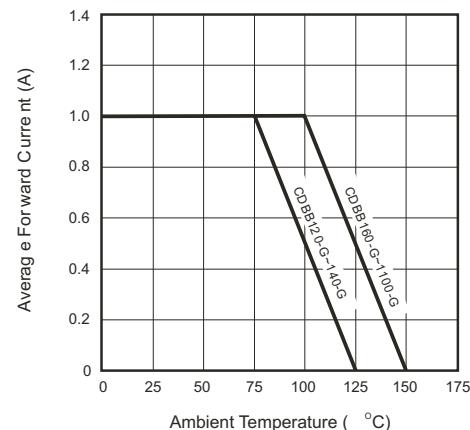


Fig.5 Non-repetitive Forward Surge Current

